

The Scattering Matrix

At “low” frequencies, we can completely characterize a **linear** device or network using an **impedance** matrix, which relates the currents and voltages at **each** device terminal to the currents and voltages at **all** other terminals.

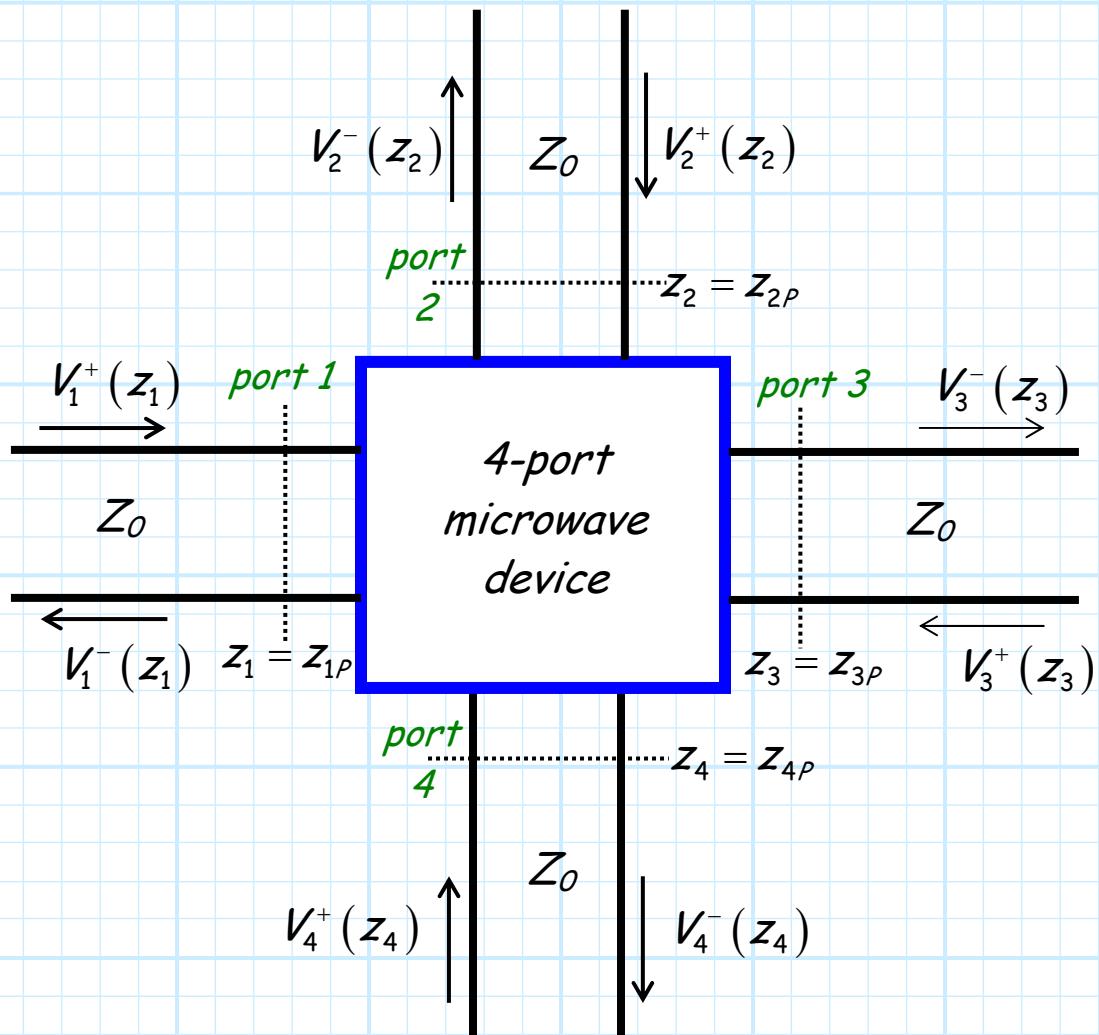
But, at microwave frequencies, it is **difficult** to measure total currents and voltages!



- * Instead, we can measure the **magnitude** and **phase** of each of the two transmission line **waves** $V^+(z)$ and $V^-(z)$.
- * In other words, we can determine the relationship between the incident and reflected wave at **each** device terminal to the incident and reflected waves at **all** other terminals.

These relationships are completely represented by the **scattering matrix**. It **completely** describes the behavior of a linear, multi-port device at a given **frequency** ω , and a given line impedance Z_0 .

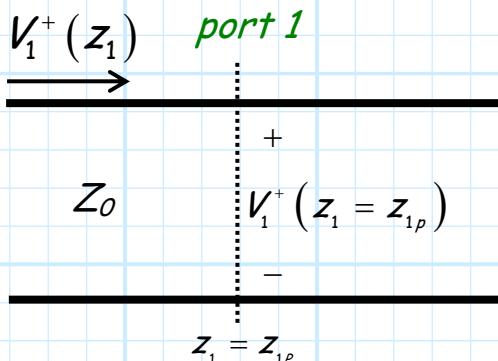
Consider now the 4-port microwave device shown below:



Note that we have now characterized transmission line activity in terms of incident and "reflected" waves. Note the negative going "reflected" waves can be viewed as the waves exiting the multi-port network or device.

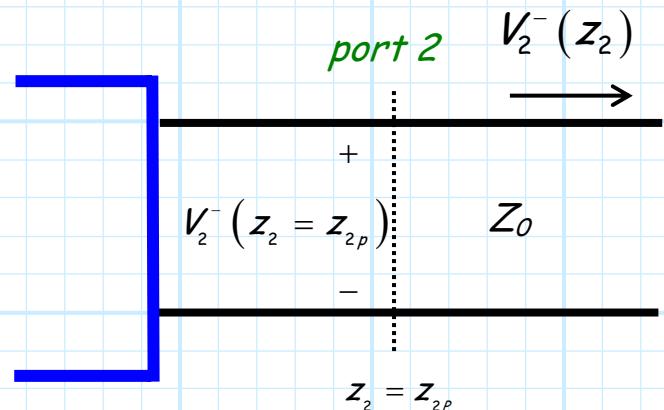
→ Viewing transmission line activity this way, we can fully characterize a multi-port device by its scattering parameters!

Say there exists an **incident wave** on **port 1** (i.e., $V_1^+(z_1) \neq 0$), while the incident waves on all other ports are known to be **zero** (i.e., $V_2^+(z_2) = V_3^+(z_3) = V_4^+(z_4) = 0$).



Say we measure/determine the voltage of the wave flowing into port 1, at the port 1 plane (i.e., determine $V_1^+(z_1 = z_{1P})$).

Say we then measure/determine the voltage of the wave flowing out of port 2, at the port 2 plane (i.e., determine $V_2^-(z_2 = z_{2P})$).



The complex ratio between $V_1^+(z_1 = z_{1P})$ and $V_2^-(z_2 = z_{2P})$ is known as the **scattering parameter S_{21}** :

$$S_{21} = \frac{V_2^-(z_2 = z_{2P})}{V_1^+(z_1 = z_{1P})} = \frac{V_{02}^- e^{+j\beta z_{2P}}}{V_{01}^+ e^{-j\beta z_{1P}}} = \frac{V_{02}^-}{V_{01}^+} e^{+j\beta(z_{2P} + z_{1P})}$$

Likewise, the scattering parameters S_{31} and S_{41} are:

$$S_{31} = \frac{V_3^-(z_3 = z_{3P})}{V_1^+(z_1 = z_{1P})} \quad \text{and}$$

$$S_{41} = \frac{V_4^-(z_4 = z_{4P})}{V_1^+(z_1 = z_{1P})}$$

We of course could **also** define, say, scattering parameter S_{34} as the ratio between the complex values $V_4^+(z_4 = z_{4P})$ (the wave **into** port 4) and $V_3^-(z_3 = z_{3P})$ (the wave **out of** port 3), given that the input to all other ports (1,2, and 3) are zero.

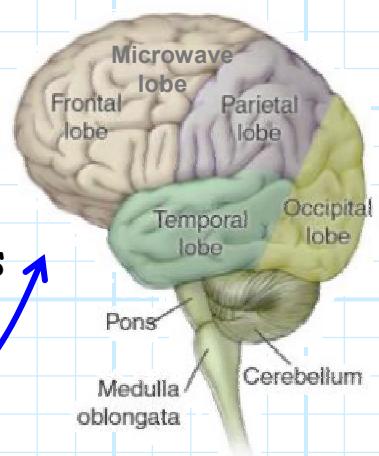
Thus, more **generally**, the ratio of the wave incident on port n to the wave emerging from port m is:

$$S_{mn} = \frac{V_m^-(z_m = z_{mP})}{V_n^+(z_n = z_{nP})} \quad (\text{given that } V_k^+(z_k) = 0 \text{ for all } k \neq n)$$

Note that frequently the port positions are assigned a **zero** value (e.g., $z_{1P} = 0$, $z_{2P} = 0$). This of course **simplifies** the scattering parameter calculation:

$$S_{mn} = \frac{V_m^-(z_m = 0)}{V_n^+(z_n = 0)} = \frac{V_{0m}^- e^{+j\beta 0}}{V_{0n}^+ e^{-j\beta 0}} = \frac{V_{0m}^-}{V_{0n}^+}$$

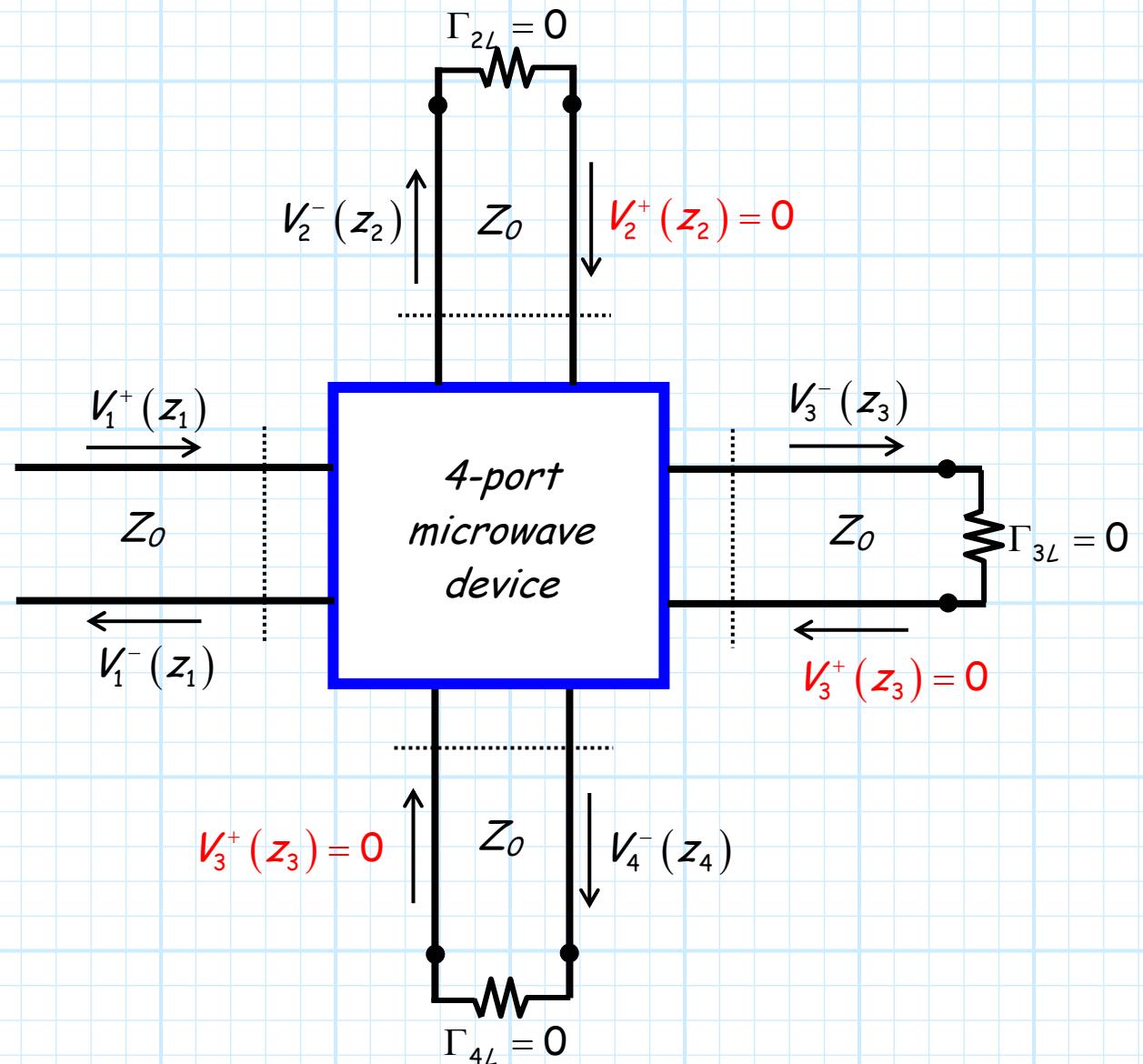
We will **generally assume** that the port locations are defined as $z_{nP} = 0$, and thus use the **above** notation. But **remember** where this expression came from!





Q: But how do we ensure that **only one** incident wave is non-zero?

A: Terminate all other ports with a matched load!



Note that if the ports are terminated in a **matched load** (i.e., $Z_L = Z_0$), then $\Gamma_{nL} = 0$ and therefore:



$$V_n^+(z_n) = 0$$

In other words, terminating a port ensures that there will be **no signal** incident on that port!

Q: Just between you and me, I think you've messed this up! In all previous handouts you said that if $\Gamma_L = 0$, the wave in the **minus** direction would be zero:

$$V^-(z) = 0 \quad \text{if} \quad \Gamma_L = 0$$

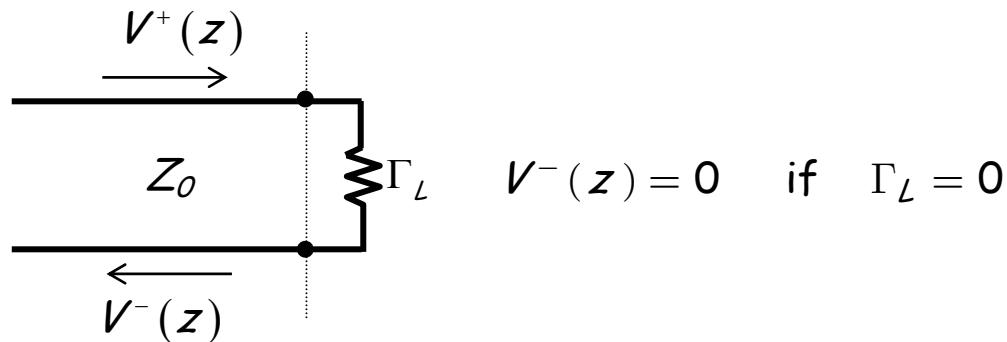
but just now you said that the wave in the **positive** direction would be zero:

$$V^+(z) = 0 \quad \text{if} \quad \Gamma_L = 0$$

Of course, there is **no way** that both statements can be correct!

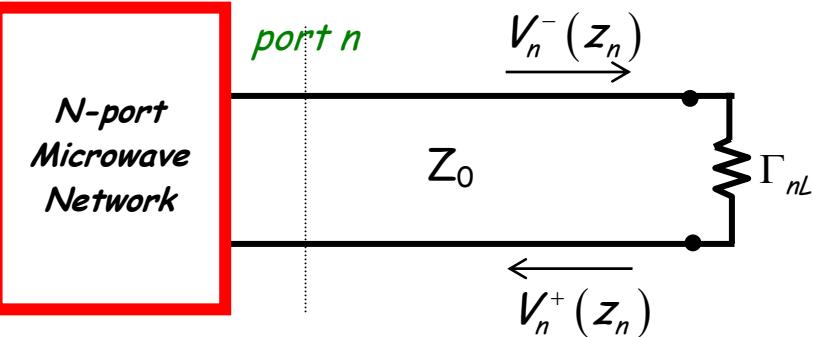
A: Actually, **both** statements are correct! You must be careful to understand the **physical definitions** of the plus and minus directions—in other words, the propagation directions of waves $V_n^+(z_n)$ and $V_n^-(z_n)$!

For example, we originally analyzed this case:



In this original case, the wave incident on the load is $V^+(z)$ (plus direction), while the reflected wave is $V^-(z)$ (minus direction).

Contrast this with the case we are now considering:



For this current case, the situation is reversed. The wave incident on the load is now denoted as $V_n^-(z_n)$ (coming out of port n), while the wave reflected off the load is now denoted as $V_n^+(z_n)$ (going into port n).

As a result, $V_n^+(z_n) = 0$ when $\Gamma_{nL} = 0$!

Perhaps we could more generally state that for some load Γ_L :

$$V^{\text{reflected}}(z = z_L) = \Gamma_L V^{\text{incident}}(z = z_L)$$



*For each case, you must be able to correctly identify the mathematical statement describing the wave **incident** on, and **reflected** from, some passive load.*

*Like most equations in engineering, the **variable names** can change, but the **physics** described by the mathematics will not!*

Now, back to our discussion of **S-parameters**. We found that if $z_{n\rho} = 0$ for all ports n , the scattering parameters could be directly written in terms of wave amplitudes V_{0n}^+ and V_{0m}^- .

$$S_{mn} = \frac{V_{0m}^-}{V_{0n}^+} \quad (\text{when } V_k^+(z_k) = 0 \text{ for all } k \neq n)$$

Which we can now equivalently state as:

$$S_{mn} = \frac{V_{0m}^-}{V_{0n}^+} \quad (\text{when all ports, except port } n, \text{ are terminated in matched loads})$$

One more important note—notice that for the ports terminated in matched loads (i.e., those ports with no incident wave), the voltage of the exiting wave is also the total voltage!

$$\begin{aligned} V_m(z_m) &= V_{0m}^+ e^{-j\beta z_m} + V_{0m}^- e^{+j\beta z_m} \\ &= 0 + V_{0m}^- e^{+j\beta z_m} \\ &= V_{0m}^- e^{+j\beta z_m} \quad (\text{for all terminated ports}) \end{aligned}$$

Thus, the value of the exiting wave at each terminated port is likewise the value of the total voltage at those ports:

$$\begin{aligned} V_m(0) &= V_{0m}^+ + V_{0m}^- \\ &= 0 + V_{0m}^- \\ &= V_{0m}^- \quad (\text{for all terminated ports}) \end{aligned}$$

And so, we can express some of the scattering parameters equivalently as:

$$S_{mn} = \frac{V_m(0)}{V_{0n}^+} \quad (\text{for terminated port } m, \text{i.e., for } m \neq n)$$

You might find this result helpful if attempting to determine scattering parameters where $m \neq n$ (e.g., S_{21} , S_{43} , S_{13}), as we can often use traditional circuit theory to easily determine the total port voltage $V_m(0)$.

However, we **cannot** use the expression above to determine the scattering parameters when $m = n$ (e.g., S_{11} , S_{22} , S_{33}).



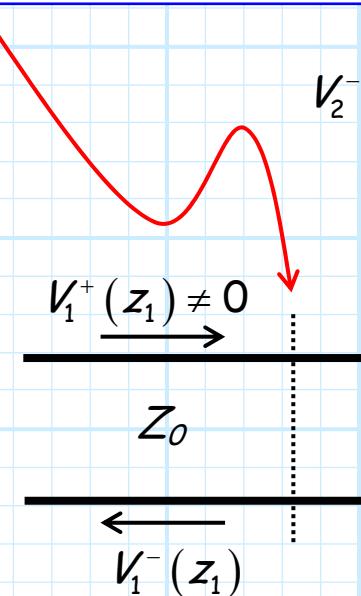
Think about this! The scattering parameters for these cases are:

$$S_{nn} = \frac{V_{0n}^-}{V_{0n}^+}$$

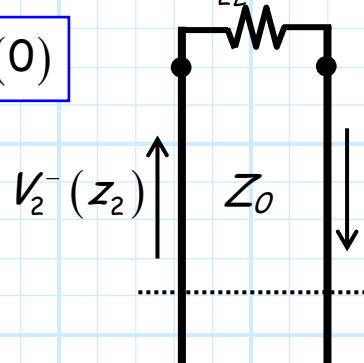
Therefore, port n is a port where there actually **is** some incident wave V_{0n}^+ (port n is **not** terminated in a matched load!).

And thus, the total voltage is **not** simply the value of the exiting wave, as **both** an incident wave and exiting wave exists at port n .

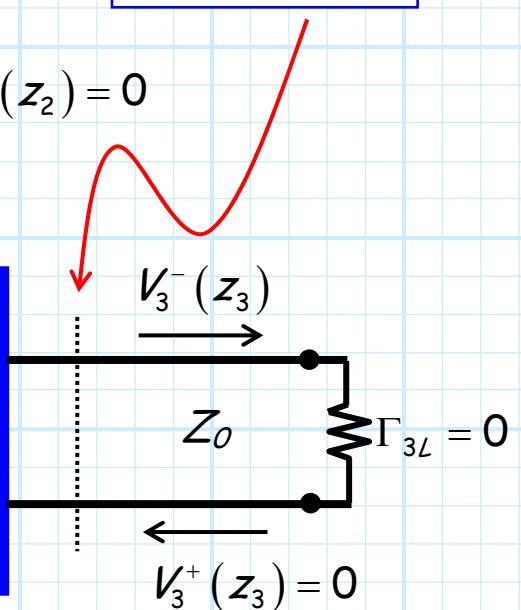
$$V_1(0) = V_1^+(0) + V_1^-(0)$$



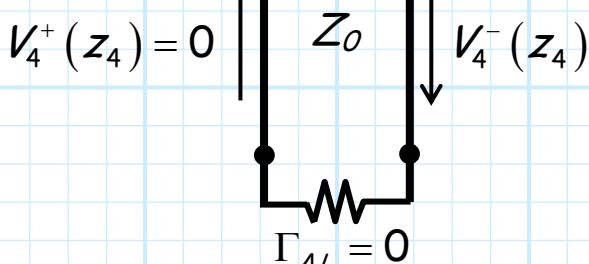
$$\Gamma_{2L} = 0$$



$$V_3(0) = V_3^-(0)$$



4-port microwave device



Typically, it is much more difficult to determine/measure the scattering parameters of the form S_{nn} , as opposed to scattering parameters of the form S_{mn} (where $m \neq n$) where there is only an exiting wave from port m !

We can use the scattering matrix to determine the solution for a more general circuit—one where the ports are not terminated in matched loads!



Q: I'm not understanding the importance scattering parameters. How are they useful to us microwave engineers?

A: Since the device is linear, we can apply superposition. The output at any port due to all the incident waves is simply the coherent sum of the output at that port due to each wave!

For example, the output wave at port 3 can be determined by (assuming $z_{np} = 0$):

$$V_{03}^- = S_{34} V_{04}^+ + S_{33} V_{03}^+ + S_{32} V_{02}^+ + S_{31} V_{01}^+$$

More generally, the output at port m of an N -port device is:

$$V_{0m}^- = \sum_{n=1}^N S_{mn} V_{0n}^+ \quad (z_{np} = 0)$$

This expression can be written in **matrix** form as:

$$\mathbf{V}^- = \mathcal{S} \mathbf{V}^+$$

Where \mathbf{V}^- is the **vector**:

$$\mathbf{V}^- = [V_{01}^-, V_{02}^-, V_{03}^-, \dots, V_{0N}^-]^T$$

and \mathbf{V}^+ is the **vector**:

$$\mathbf{V}^+ = [V_{01}^+, V_{02}^+, V_{03}^+, \dots, V_{0N}^+]^T$$

Therefore \mathcal{S} is the **scattering matrix**:

$$\mathcal{S} = \begin{bmatrix} S_{11} & \dots & S_{1n} \\ \vdots & \ddots & \vdots \\ S_{m1} & \dots & S_{mn} \end{bmatrix}$$

The scattering matrix is a N by N matrix that **completely characterizes** a linear, N -port device. Effectively, the scattering matrix describes a multi-port device the way that Γ_L describes a single-port device (e.g., a load)!



But **beware!** The values of the scattering matrix for a particular device or network, just like Γ_L , are **frequency dependent!** Thus, it may be more instructive to **explicitly write:**

$$\mathcal{S}(\omega) = \begin{bmatrix} S_{11}(\omega) & \dots & S_{1n}(\omega) \\ \vdots & \ddots & \vdots \\ S_{m1}(\omega) & \dots & S_{mn}(\omega) \end{bmatrix}$$

Also realize that—also just like Γ_L —the scattering matrix is dependent on **both the device/network and the Z_0 value of the transmission lines connected to it.**

Thus, a device connected to transmission lines with $Z_0 = 50\Omega$ will have a **completely different scattering matrix** than that same device connected to transmission lines with $Z_0 = 100\Omega$!!!